

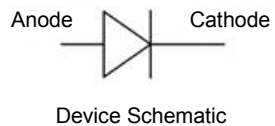
## Product Summary

$V_{RRM}$ (V)	$I_O$ (A)	$V_F$ Max (V)	$I_R$ Max ( $\mu$ A)
20	1.0	0.44	100

## Description and Applications

The SDM1U20CSP is a 20V, 1A Schottky barrier rectifier that is optimized for low, forward-voltage drop and low leakage current. Housed in a compact chip scale package (CSP), the SDM1U20CSP occupies only 0.84 mm<sup>2</sup> board-space with low profile. The low thermal resistance enables designers to meet design challenges of increasing efficiency while at the same time reducing board space. It is ideally suited for use in portable applications as:

- Blocking Diodes
- Boost Diodes
- Switching Diodes
- Reverse Protection Diodes

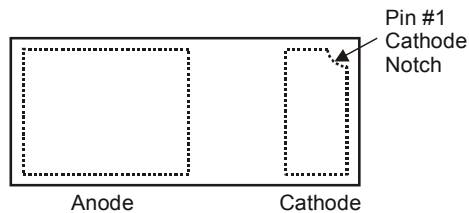


## Features and Benefits

- Low Forward Voltage ( $V_F$ ) Minimizes Conduction Losses and Improves Efficiency
- Reduced High-Temperature Reverse Leakage  
Increased Reliability against Thermal Runaway Failure in High Temperature Operation
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen- and Antimony-Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](#) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

## Mechanical Data

- Case: X3-WLB1406-2
- Moisture Sensitivity: Level 1 per J-STD-020
- Polarity: Cathode Dot
- Weight: 0.001 grams (Approximate)



## Ordering Information (Note 4)

Part Number	Case	Packaging
SDM1U20CSP-7	X3-WLB1406-2	5,000/Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information

X3-WLB1406-2

Pin 1



X8=Product Type Marking Code  
 YM=Date Code Marking  
 Y=Year (ex: G=2019)  
 M=Month (ex: N=November)  
 Dot Denotes Cathode Pin

### Date Code Key

Year	2014	2015	2016	2017	2018	2019	2020
Code	B	C	D	E	F	G	H

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

## Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	20	V
Average Rectified Output Current	I <sub>O</sub>	1.0	A
Repetitive Peak Forward Current (Pulse Wave = 1 Sec, Duty Cycle = 66%)	I <sub>FRM</sub>	5.0	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	18	A

## Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Ambient (Note 5)	R <sub>θJA</sub>	140	°C/W
Typical Thermal Resistance Junction to Ambient (Note 6)	R <sub>θJA</sub>	73	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Forward Voltage Drop	V <sub>F</sub>	—	—	0.39	V	I <sub>F</sub> = 0.5A
		—	—	0.44		I <sub>F</sub> = 1.0A
Reverse Current (Note 7)	I <sub>R</sub>	—	—	25	μA	V <sub>R</sub> = 10V
		—	—	100		V <sub>R</sub> = 20V
Junction Capacitance	C <sub>J</sub>	—	76	—	pF	V <sub>R</sub> = 4V, f = 1.0MHz

Notes: 5. Device mounted on FR-4 PCB, 2oz. Copper, minimum recommended pad layout per <http://www.diodes.com/package-outlines.html>.  
 6. Device mounted on FR-4 PCB, 2oz. 1 square inch Copper.  
 7. Short duration pulse test used to minimize self-heating effect.

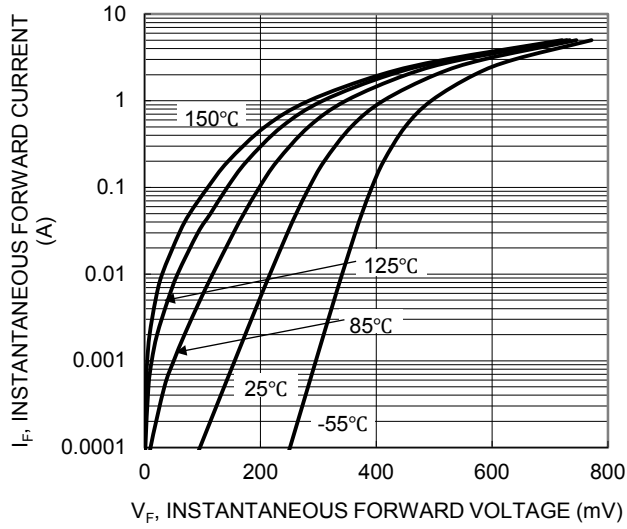


Figure 1. Typical Forward Characteristics

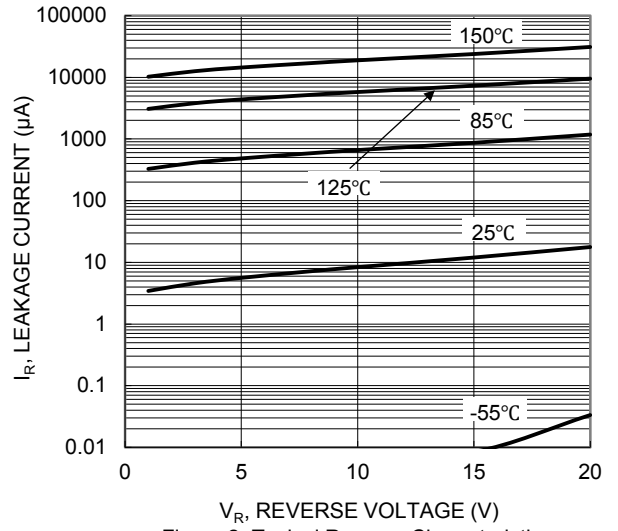


Figure 2. Typical Reverse Characteristics

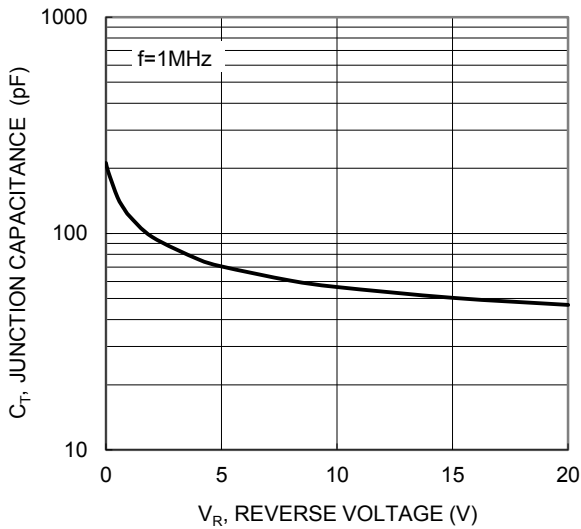


Figure 3. Typical Junction Capacitance

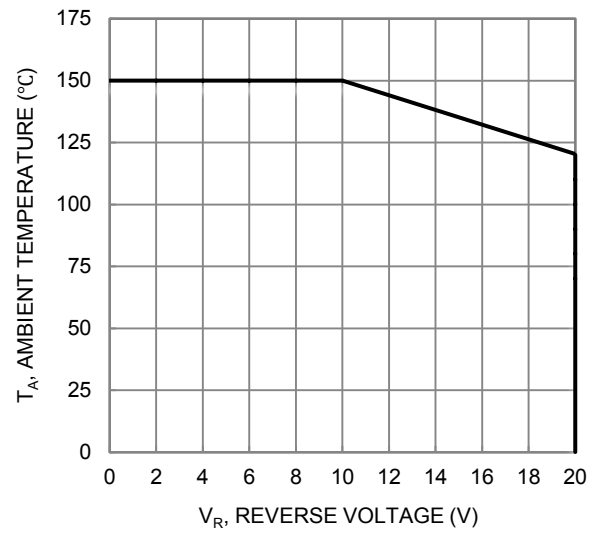
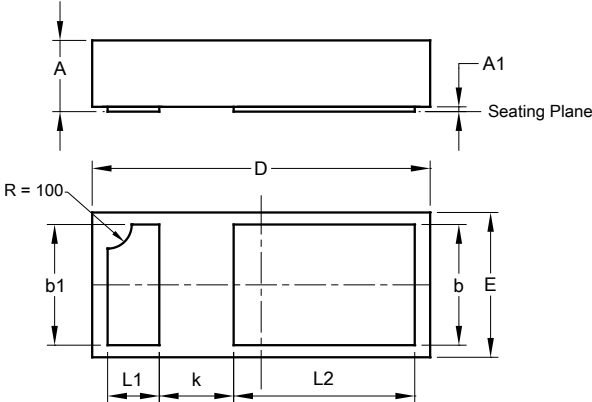


Figure 4. Operating Temperature Derating

**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**X3-WLB1406-2**

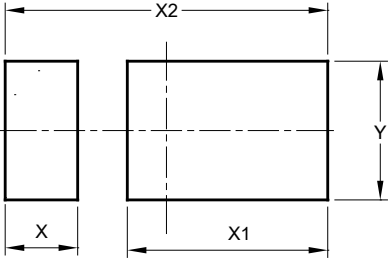


X3-WLB1406-2			
Dim	Min	Max	Typ
A	0.250	0.300	0.275
A1	0.000	0.015	-
b	0.45	0.55	-
b1	0.45	0.55	-
D	1.37	1.43	1.40
E	0.57	0.63	0.60
k	-	-	0.30
L1	0.20	0.26	-
L2	0.70	0.80	-
All Dimensions in mm			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**X3-WLB1406-2**



Dimensions	Value (in mm)
X	0.304
X1	0.840
X2	1.352
Y	0.580

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